

## High voltage fast-switching NPN power transistor

Datasheet - production data

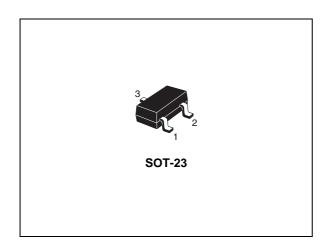
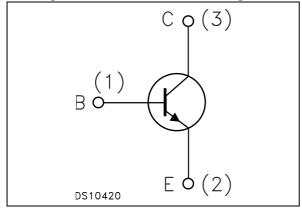


Figure 1. Internal schematic diagram



#### **Features**

- Excellent hFE linearity up to 50 mA
- Miniature SOT-23 plastic package for surface mounting circuits
- · Tape and reel packaging
- The PNP complementary type is STR2550

#### **Applications**

• LED driving

#### **Description**

This device is a high voltage fast-switching NPN power transistor, manufactured using diffused collector planar technology for high switching speeds.

It employs a base island structure with planar edge termination to enhance switching speeds, while maintaining a wide RBSOA.

**Table 1. Device summary** 

| Order code | Marking | Package | Packing       |
|------------|---------|---------|---------------|
| STR1550    | 1550    | SOT-23  | Tape and reel |

Contents STR1550

## **Contents**

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STR1550 Electrical ratings

# 1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol  | Parameter                                      | Value      | Unit |
|---|--|------------|------|
| $V_{CBO}$   | Collector-base voltage (I <sub>E</sub> = 0)    | 500        | V    |
| V <sub>CEO</sub> Collector-emitter voltage (I <sub>B</sub> = 0) |  | 500        | V    |
| V <sub>EBO</sub> Emitter-base voltage (I <sub>C</sub> = 0)      |  | 9          | V    |
| I <sub>C</sub>  | Collector current                              | 0.5        | Α    |
| I <sub>CM</sub>   | Collector peak current (t <sub>P</sub> < 5 ms) | 1          | Α    |
| P <sub>TOT</sub>  | Total dissipation at T <sub>amb</sub> = 25 °C  | 500        | mW   |
| T <sub>STG</sub>  | Storage temperature                            | -65 to 150 | °C   |
| T <sub>J</sub> Max. operating junction temperature              |  | 150        | °C   |

Table 3. Thermal data

| Symbol                           | Parameter                               | Value | Unit |
|----------------------------------|---|-------|------|
| R <sub>thJA</sub> <sup>(1)</sup> | Thermal resistance junction-ambient max | 250   | °C/W |

<sup>1.</sup> Device mounted on PCB area of 1 cm<sup>2</sup>.

Electrical characteristics STR1550

### 2 Electrical characteristics

 $T_{case} = 25$  °C unless otherwise specified.

**Table 4. Electrical characteristics** 

| Symbol  | Parameter   | Test conditions                               | Min. | Тур. | Max. | Unit |
|---|---|---|------|------|------|------|
| I <sub>CBO</sub> Collector cut-off current (I <sub>E</sub> = 0)                   |   | V <sub>CB</sub> = 500 V                       |      |      | 10   | μΑ   |
| V <sub>(BR)CBO</sub> Collector-base breakdown voltage (I <sub>E</sub> = 0)        |   | Ι <sub>C</sub> = 100 μΑ                       | 500  |      |      | V    |
| V <sub>(BR)CEO</sub> (1) Collector-emitter breakdown voltage (I <sub>B</sub> = 0) |   | I <sub>C</sub> = 1 mA                         | 500  |      |      | V    |
| V <sub>(BR)EBO</sub>  | Emitter-base breakdown voltage (I <sub>C</sub> = 0) | I <sub>E</sub> = 100 μA                       | 12   |      |      | V    |
| V <sub>CE(sat)</sub> (1)  | Collector-emitter saturation voltage                | $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$     |      |      | 0.2  | V    |
| VCE(sat) ` ′  |   | $I_C = 50 \text{ mA}, I_B = 6 \text{ mA}$     |      |      | 0.3  | V    |
| V <sub>BE(sat)</sub> (1)  | Base-emitter saturation voltage                     | I <sub>C</sub> = 50 mA, I <sub>B</sub> = 5 mA |      |      | 0.9  | V    |
| V <sub>BE(on</sub> ) Base-emitter on voltage                                      |   | $I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}$  |      |      | 0.9  | V    |
| h <sub>FE</sub> <sup>(1)</sup>  | DC current gain                                     | I <sub>C</sub> = 1 mA, V <sub>CE</sub> = 10 V | 100  |      |      |      |
|   |   | $I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}$  | 100  |      | 300  |      |
|   |   | $I_C = 100 \text{ mA}, V_{CE} = 10 \text{ V}$ | 10   |      |      |      |

<sup>1.</sup> Pulse test: pulse duration ≤ 300 µs, duty cycle ≤ 2%

-55°C

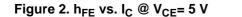
100°C

0.1

Ic(A)

AM17433v1

### 2.1 Electrical characteristics (curves)

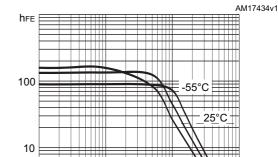


hfe

100

10

0.001



0.01

0.001

100°C

0.1

Figure 3. h<sub>FE</sub> vs. I<sub>C</sub> @ V<sub>CE</sub>= 10 V



Ic(A)

0.01

Figure 4.  $V_{CE(sat)}$  vs.  $I_C$  @  $h_{FE}$ = 5

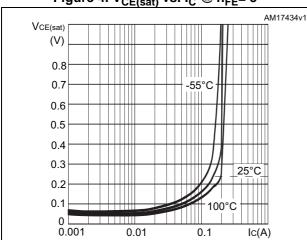


Figure 5.  $V_{CE(sat)}$  vs.  $I_C$  @  $h_{FE}$ = 10

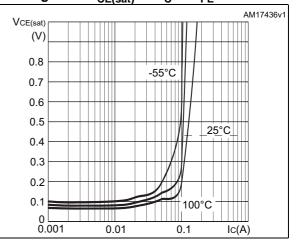


Figure 6.  $V_{BE(sat)}$  vs.  $I_C$  @  $h_{FE}$ = 5

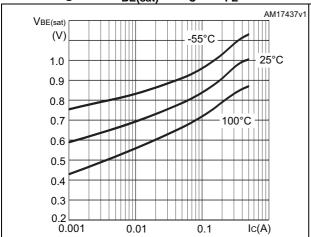


Figure 7.  $V_{BE(sat)}$  vs.  $I_C$  @  $h_{FE}$ = 10

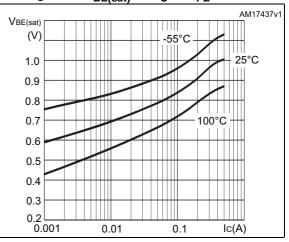
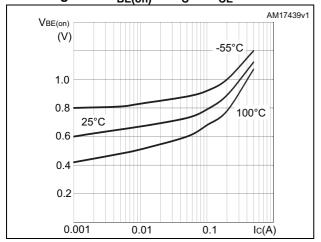


Figure 8.  $V_{BE(on)}$  vs.  $I_C @ V_{CE}$ = 10 V



# 3 Package mechanical data

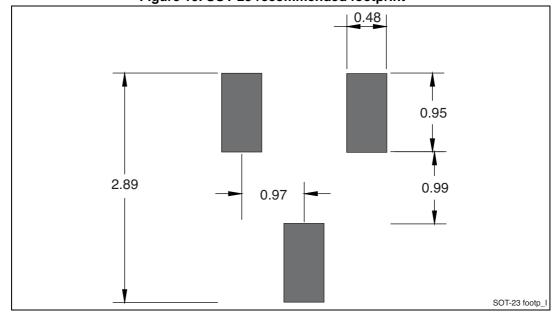
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Figure 9. SOT-23 drawings

Table 5. SOT-23 mechanical data

| Dim. | mm    |      |      |  |
|------|-------|------|------|--|
|      | Min.  | Тур. | Max. |  |
| А    | 0.89  |      | 1.40 |  |
| A1   | 0     |      | 0.10 |  |
| В    | 0.30  |      | 0.51 |  |
| С    | 0.085 |      | 0.18 |  |
| D    | 2.75  |      | 3.04 |  |
| е    | 0.85  |      | 1.05 |  |
| e1   | 1.70  |      | 2.10 |  |
| E    | 1.20  |      | 1.75 |  |
| Н    | 2.10  |      | 3.00 |  |
| L    |       | 0.60 |      |  |
| S    | 0.35  |      | 0.65 |  |
| L1   | 0.25  |      | 0.55 |  |
| а    | 0°    |      | 8°   |  |

Figure 10. SOT-23 recommended footprint (a)



a. Dimensions are in mm.



Revision history STR1550

# 4 Revision history

Table 6. Document revision history

| Date        | Revision | Changes  |
|-------------|----------|--|
| 17-Oct-2011 | 1        | Initial release  |
| 05-Jun-2012 | 2        | Modified: features, <i>Table 4</i> (V <sub>CE(sat)</sub> values, h <sub>FE</sub> test conditions and values)   |
| 21-May-2013 | 3        | <ul> <li>Modified: Table 4 (V<sub>BE(sat)</sub> values, h<sub>FE</sub> max. value and V<sub>(BR)EBO</sub> min. value</li> <li>Inserted: V<sub>BE(on)</sub></li> <li>Modified: Table 4 (h<sub>FE</sub> max. value)</li> <li>Added new section: Electrical characteristics (curves)</li> </ul> |
| 27-May-2013 | 4        | Document status promoted from preliminary to production data   |
| 09-May-2014 | 5        | Updated Table 1: Device summary and Section 3: Package mechanical data   |

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